



74HCT594

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

The 74HCT594 is a high speed CMOS device that is designed to be pin compatable with 74LS low power Schottky types.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low the shift register reset function ($\overline{\text{SHR}}$) sets all shift register values to zero and is independent of all clocks. Also when asserted low the storage register reset function ($\overline{\text{STR}}$) sets all shift register values to zero and is independent of all clocks

Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). The storage resister includes output Q7S which is used for cascading information between devices. As the information moves into the storage register, it is asserted on the push-pull outputs Q0-Q7

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Sinks or sources 8mA at V_{CC} = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- · Inputs accept up to 6.0V
- · ESD Protection Tested per JESD 22

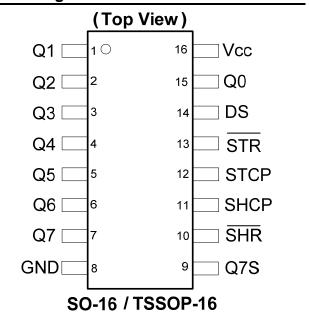
Exceeds 200-V Machine Model (A115-A)

Exceeds 2000-V Human Body Model (A114-A)

Exceeds 1000-V Charged Device Model (C101C)

- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- · Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed.
- · Wide array of products such as:
 - o Computer peripherals
 - Appliances
 - Industrial control

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and < 1000 ppm antimony compounds.

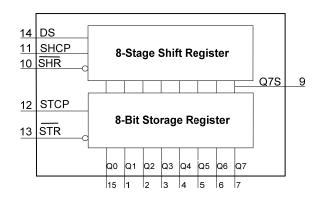
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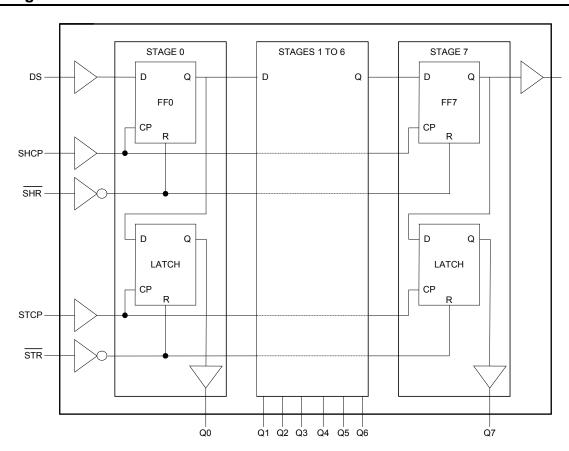
Pin Descriptions

Pin Number	Pin Name	Description
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	SHR	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	STR	Storage Register Reset active low
14	DS	Serial Data Input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram

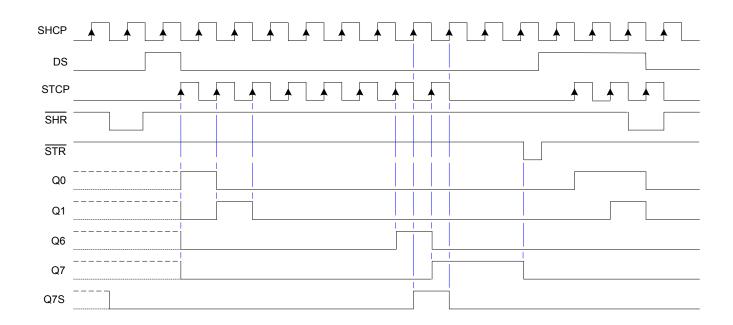




Functional Description and Timing Diagram

	Control			Input	Ou	ıtput	Function		
SHR	STR	SHCP	STCP	DS	Q7S	Qn	Function		
L	Х	Х	Х	Х	L	NC	Clear Shift Register		
Х	L	Х	Х	Х	NC	L	Clear Storage Register		
Н	Х	1	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q _s shifted		
Н	Н	х	1	х	NC	Qs	Contents of shift register moved to starge register all $Q_S \rightarrow Q_N$		
Н	Н	1	1	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.		

H=HIGH voltage state L=LOW voltage state ↑=LOW to HIGH transition X= don't care – high or low (not floating) NC= No change





Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.

Symbol	Desc	ription	Rating	Unit
ESD HBM	Human Body Model ESD Protection	1	2	KV
ESD CDM	Charged Device Model ESD Protec	tion	1	KV
ESD MM	Machine Model ESD Protection		200	V
Vcc	Supply Voltage Range		-0.5 to 7.0	V
VI	Input Voltage Range		-0.5 to 7.0	V
Vo	Voltage applied to output in high or	low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < -0.5V		-20	mA
I _{IK}	Input Clamp Current VI > V _{cc} +0	.5V	20	mA
Іок	Output Clamp Current Vo<-0.5V		-20	mA
lok	Output Clamp Current V _O > V _{CC} +	0.5V	20	mA
		Q7 standard output	+/- 25	mA
lo	Continuous output current	Qn bus driver outputs	+/- 35	mA
Icc	Continuous current through V _{cc}		70	mA
I _{GND}	Continuous current through GND	-70	mA	
TJ	Operating Junction Temperature	-40 to +150	°C	
T _{STG}	Storage Temperature	-65 to +150	°C	
P _{TOT}	Total Power Dissipation		500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{cc}	Supply Voltage	ľ	4.5	5.5	V
V_{l}	Input Voltage	ľ	0	5.5	V
Vo	Output Voltage	Active Mode	0	V_{CC}	V
Δt/ΔV	Input transition rise or fall rate	$V_{CC} = 4.5V \text{ to } 5.5V$	ı	500	ns/V
T_A	Operating free-air temperature	1	-40	+125	°C

Notes: 5. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

			•	.,	-	Γ _A = +25°	С	-40°C	to +85°C	-40°C to +125°C		
Symbol	Parameter	Test Cond	itions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	High-level Input Voltage	_		4.5 V to 5.5 V	2.0	1.6	_	2.0	-	2.0	-	V
V _{IL}	Low-level input voltage	_		4.5 V to 5.5 V	_	-	0.8	_	0.8	_	0.8	V
	High Level Output Voltage	$I_{OH} = -20\mu A$ All outputs		4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
V _{OH}	Q7S output	I _{OH} = -4.0mA	١	4.5 V	3.98	4.32	_	3.85	_	3.7	-	
	Qn Bus Outputs	I _{OH} = -6.0 m/	A	4.5 V	3.98	4.32	_	3.85	-	3.7	ı	_
	Low-level Output Voltage	I _{OL} = 20μA All outputs		4.5 V	-	0	0.1	ı	0.1	_	0.1	V
V_{OL}	Q7S output	I _{OL} = 4.0mA		4.5 V	-	0.15	0.26	-	0.33	-	0.4	
	Qn Bus Outputs	I _{OL} = 6.0mA		4.5 V	-	0.16	0.26	-	0.33	-	0.4	_
lı	Input Current	V _I =GND to 5.5 V		5.5 V	-	_	±0.1	-	± 1	-	± 1	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC} = I_O = 0$		5.5 V	-	_	8.0	ı	80	ı	160	μA
ΔΙ _{СС}	Additional Supply Current	Pin V _I = V _{cc} -2.1 V	PINS SHCP SHST SHR STR	4.5V to 5.5 V	-	100	240	-	300	-	300	μA
		or GND I _O =0	PIN DS	4.5V to 5.5 V	_	75	120	_	150	_	150	
C _i	Input Capacitance	V _i = V _{CC} or GND	5.5 V	_	3.5	10	-	-	10	-	10	pF

Operating Characteristics

Parameter		Test Conditions	V _{CC} = 5V	Unit
C_{pd}	·	$f = 1$ MHz all outputs switching-no load $V_1 = GND TO V_{CC} - 1.5V$	51	pF



Switching Characteristics

Symbol /	Die -	Test	W		T _A = +25°C		-40°C t	o +85°C	-40°C to +125°C		Hnit
Parameter	Pins	Conditions	V _{cc}	Min	Тур.	Max	Min	Max	Min	Max	Unit
f _{MAX} Maximum Frequency	SHCP or STCP	Figure 2 C _L =15pF	5.0 V	30	92	_	24	-	20	_	MHz
	SHCP HIGH or LOW	Figure 2 C _L =50pF	4.5 V	16	4	_	20	_	24	_	
t _W Pulse Width	STCP HIGH or LOW	Figure 2 C _L =50pF	4.5 V	16	4	-	20	-	24	_	ns
	SHR and STR HIGH or LOW	Figure 2 C _L =50pF	4.5 V	16	6	_	20	_	24	_	
	DS to SHCP	Figure 2 C _L =50pF	4.5 V	20	4	_	25	_	30	_	
t _{SU} Set-up Time	SHR to STCP	Figure 2 C _L =50pF 2	4.5 V	20	6	_	25	_	30	_	ns
	SHCP to STCP	Figure 2 C _L =50pF	4.5 V	20	7	_	25	_	30	_	
	SHCP to	Figure 2 C _L =50p	4.5 V	_	18	32	-	40	_	48	
t _{PD}	Q7S	Figure 2 C _L =15pF	5.0 V	_	15	-	_	_	-	-	
Propagation Delay	STCP to Qn	Figure 2 C _L =50p	4.5 V	_	18	32	_	40	_	48	ns
STCP to QII	STOP to QII	Figure 2 C _L =15p	5.0 V	_	15	_	_	_	_	_	
t _H Hold Time	DS to SHCP	Figure 2	4.5 V	5	-3	_	6	_	7	_	ns
t _{REC} Recovery Time	SHR to SHCP and STR to STCP	Figure 2	4.5 V	10	-5	_	13	_	15	_	ns



Switching Characteristics (cont.)

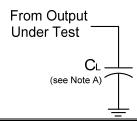
Symbol /		Test	,	7	Γ _A = +25°(С	-40°C to	+85°C	-40°C to	+125°C	1114
Parameter	Pins	Conditions V _{cc}	Min	Тур.	Max	Min	Max	Min	Max	Unit	
	CUD to 070	Figure 2 C _L =50pF	4.5 V	_	17	30	_	38	_	45	
t _{PHL}	SHR to Q7S	Figure 2 C _L =15pF	5.0 V	_	14	_	_	_	_	_	ns
Propagation Delay		Figure 2 C _L =50pF	4.5 V	_	17	30	_	38	_	45	
	STR to Qn	Figure 2 C _L =15pF	5.0 V	_	14	-	_	-	_	_	ns
t _{THL}	Serial data output Q7S	Figure 2 C _L =50pF	4.5 V	-	7	15	_	19	_	22	ns
t _{TLH} Transition Times	Parallel Data Outputs Q _N	Figure 2 C _L =50pF	4.5 V	_	5	12	_	15	_	18	ns

June 2013

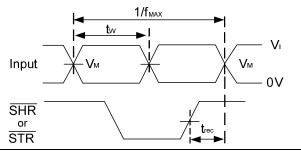
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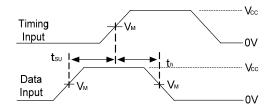
Parameter Measurement Information



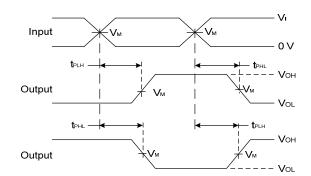
V _{cc}	lnį	outs	V _M
	Vı	t _r /t _f	
4.5V	V _{cc}	6ns	V _{cc} /2
5.0V	V _{cc}	6ns	V _{CC} /2



Voltage Waveform
Pulse Duration and Recovery Time



Voltage Waveform Set-up and Hold Times



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

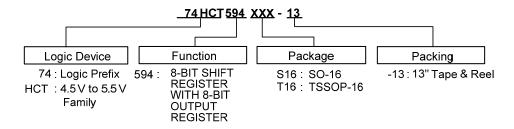
Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 10 MHz
- C. Inputs are measured separately one transition per measurement
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 2. Load Circuit and Voltage Waveforms



Ordering Information

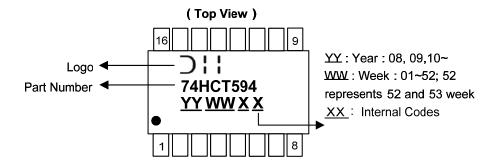


Davisa	Daalaana Cada	Packaging	7" Tape and	Reel (Note 6)
Device	Package Code		Quantity	Part Number Suffix
74HCT594S16-13	S16	SO-16	2500/Tape & Reel	-13
74HCT594T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Notes: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-16, TSSOP-16



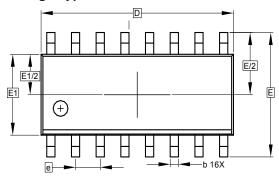
Part Number	Package		
74HCT594S16	SO-16		
74HCT594T16	TSSOP-16		



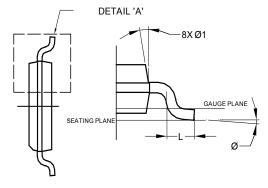
Package Outline Dimensions (All Dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(1) Package Type: SO-16

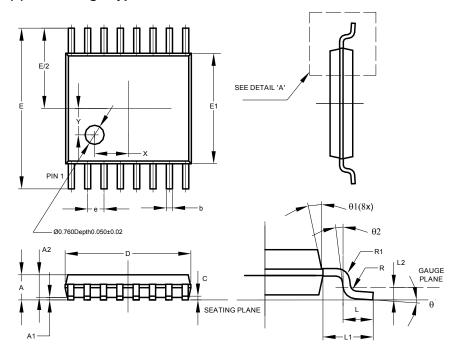






	SOIC-16								
Dim	Min	Max	Тур						
Α	_	1.75	_						
A1	0.10	0.25	-						
b	0.31	0.51	-						
С	0.10	0.25	-						
D	9.80	10.00	-						
Е	5.80	6.20	-						
E1	3.80	4.00	-						
е	-	_	1.27						
L	0.40	1.27	-						
Ø	0°	8°	-						
Ø1	5°	15°	-						
All	Dimens	ions in i	mm						

(2) Package Type: TSSOP-16



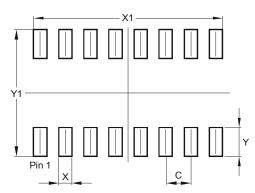
TSSOP-16				
Dim	Min	Max	Тур	
Α	-	1.08	-	
A 1	0.05	0.15	-	
A2	0.80	0.93	-	
b	0.19	0.30	-	
C	0.09	0.20	1	
D	4.90	5.10	-	
Е	6.40 BSC			
E1	4.30	4.50	-	
е	0.65 BSC			
L	0.45	0.75	1	
L1	1.00 REF			
L2	0.25 BSC			
R	0.09	1	1	
R1	0.09	-	-	
X	1	ı	1.350	
Υ	ı	1	1.050	
Θ	0°	8°	-	
Θ1	5°	15°	_	
Θ2	0°	_	-	
All Dimensions in mm				



Suggested Pad Layout

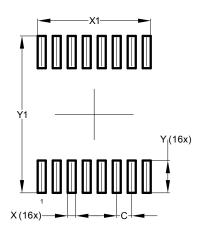
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)	
С	1.270	
X	0.670	
X1	9.560	
Y	1.450	
Y1	6.400	

Package Type: TSSOP-16



Dimensions	Value (in mm)	
С	0.650	
Х	0.350	
X1	4.900	
Y	1.400	
V1	6.800	



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